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SOT-23 .> / / xJ’ PNP f â 'ož Silicon PNP Digital Transistor in a SOT-23 Plastic Package.

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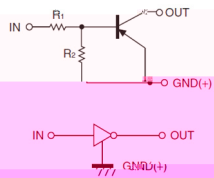
With built-in bias resistors, simplify circuit design, reduce a quantity of parts and manufacturing process,HF Product.

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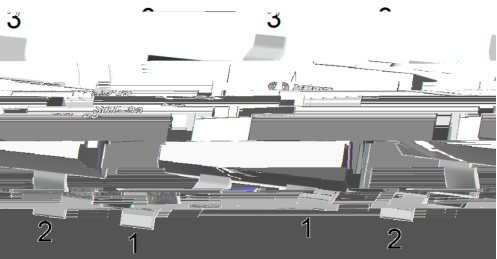
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Switching applications, interface circuit and driver circuit applications.

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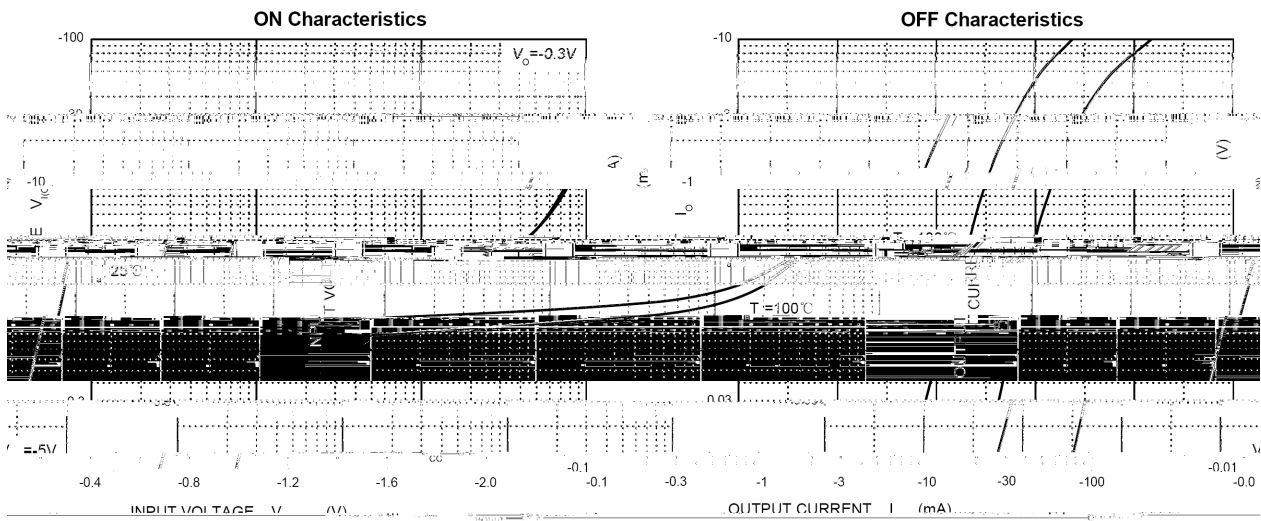
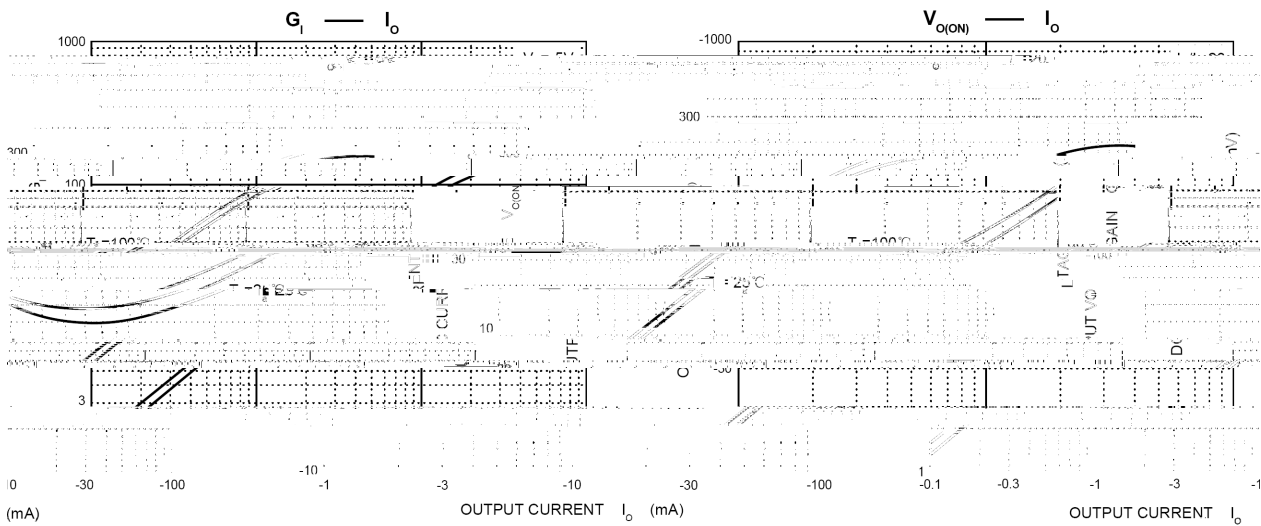
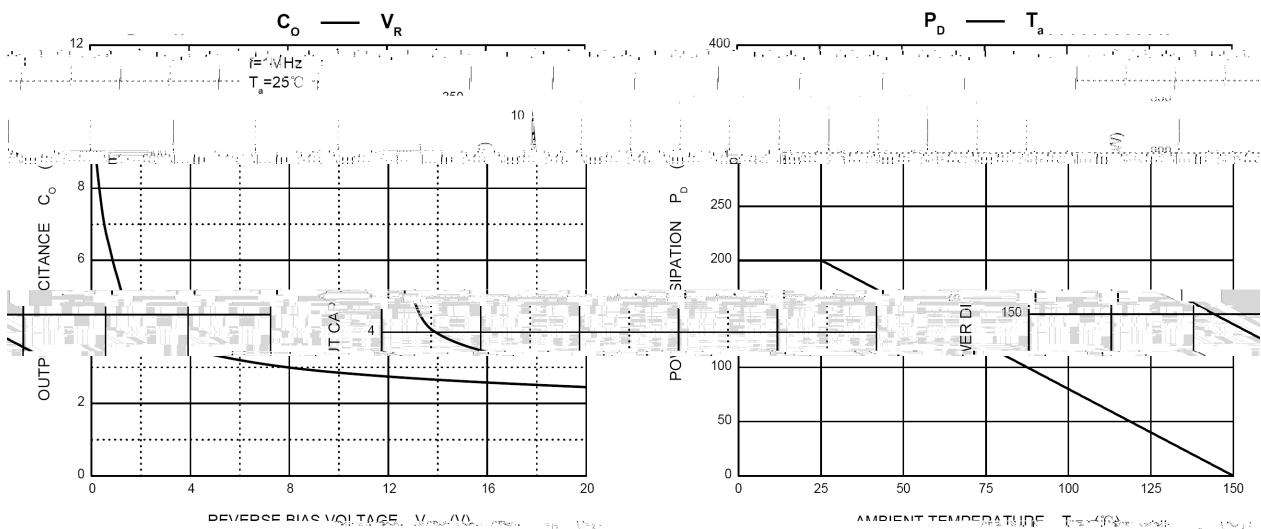
PIN1 y IN PIN 2 y GND PIN 3 y OUT

Z Ü B , M V

Marking	H14
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@ f Parameter	... Z Symbol	f > Rating	% y Unit
Output Voltage	V _{CC}	-50	V
Input Voltage	V _{IN}	10	V
		-40	V
Output Current	I _O	-50	mA
Peak Collector Current	I _{CM}	-100	mA
Power Dissipation	P _D	200	mW
Junction Temperature	T _J	-55 150	

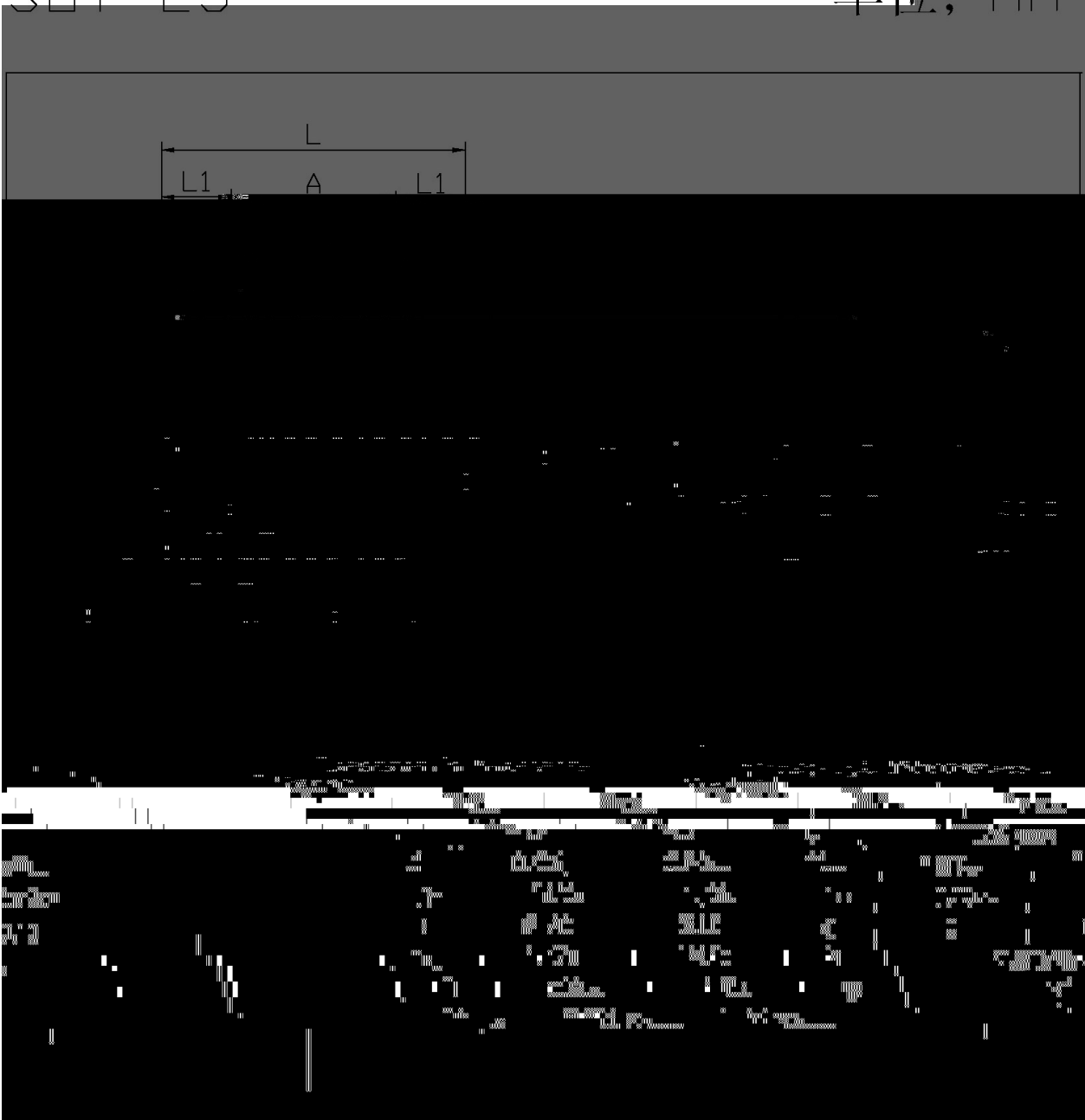
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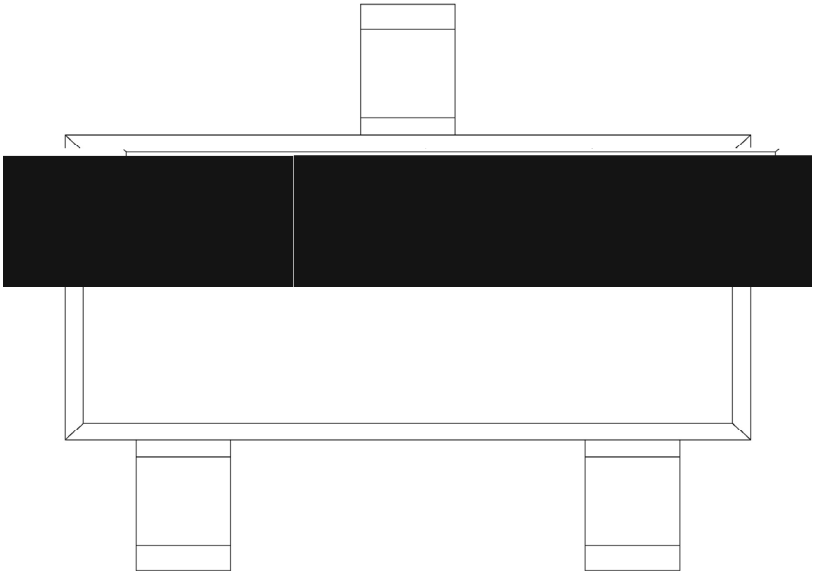
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SOT-23

单位; mm



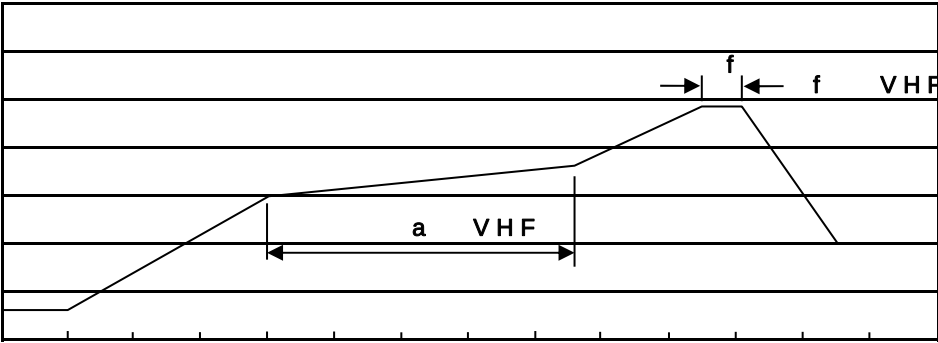
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7HPSHUDWXUH



7LPH VHF

a ç y

- 10• Ä ½ “† 150 ½180 - k ž • 60 ½90sec;
- 20• Q > “† 245 r5 - k ž • 4 Ò 5 r0.5sec;
- 30•D N ò i Ò 0 ,† 2 ½10 - /sec.

Note:

- 1.Preheating:150~180 - , Time:60~90sec.
- 2.Peak Temp.:245 r5 - , Duration:5 r0.5sec.
- 3. Cooling Speed: 2~10 - /sec.

ÂD /Cã p ¯ »]

“† y 260 r5 - ž • y 10 r1 sec. Temp.:260±5 Time:10±1 sec

G P á

2 & x / REEL

Package Type 7>û ~ E	Units ;>û H					Dimension ;>û p . (unit Åmm³)		
	Units/Reel /-	Reels/Inner Box -- /-	Units/Inner Box /-	Inner Boxes/Outer Box - /1ç	Units/Outer Box /1ç	Reel	Inner Box	Outer Boxç
SOT-23	3,000	10	30,000	6	180,000	7 T×8	180×120×180	390×385×205

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